

10-13 GHz Gain 20 dB Low Noise Amplifier

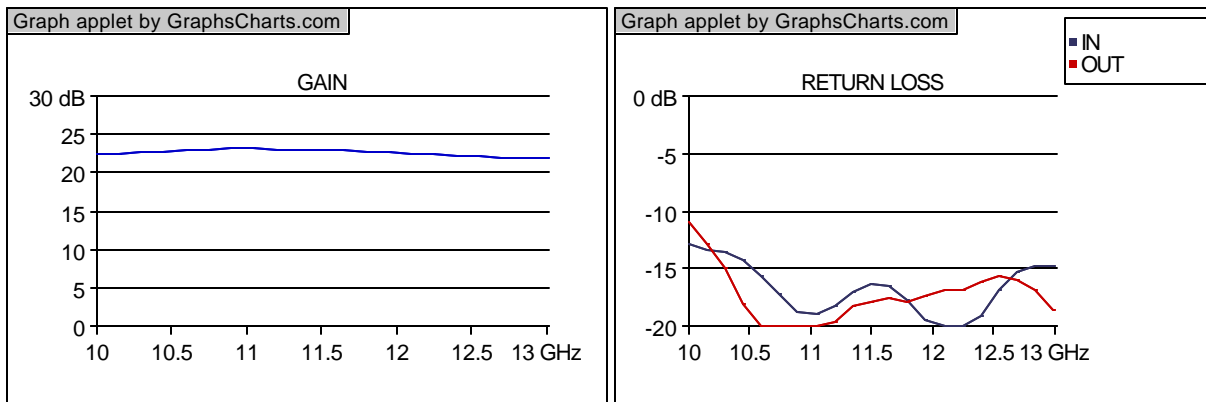
Features:

- Thin Film MIC Hybrid Process
- Field Replaceable SMA Connectors
- Reverse Bias Protection

Electrical Performance

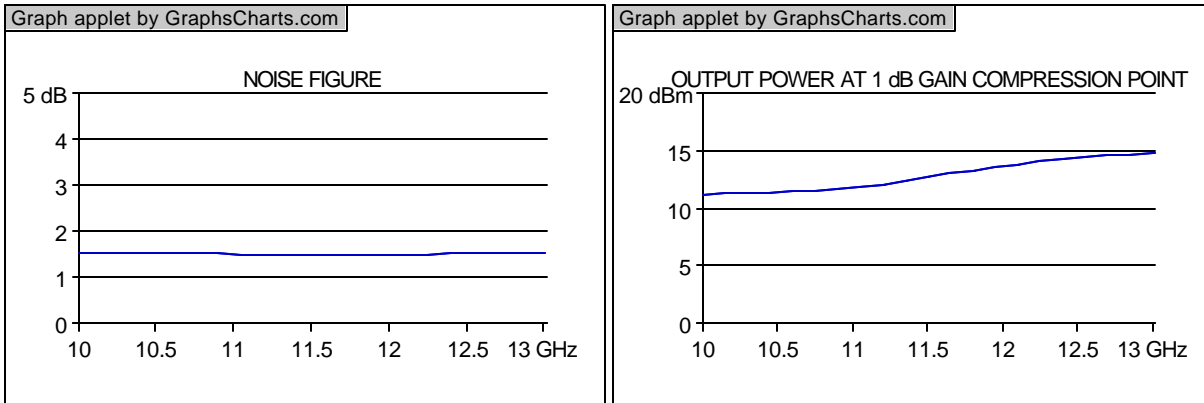
Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	10		13	GHz	
Gain	20	22		dB	
Gain Flatness			1	dB(+/-)	
Power @ 1dB Gain Compression Point	10.5			dBm	
Noise Figure			1.8	dB	
VSWR Input			2.0		
VSWR Output			2.0		
DC Supply Voltage	9	12	15	V	
Supplied Current			70	mA	

Typical Test Data

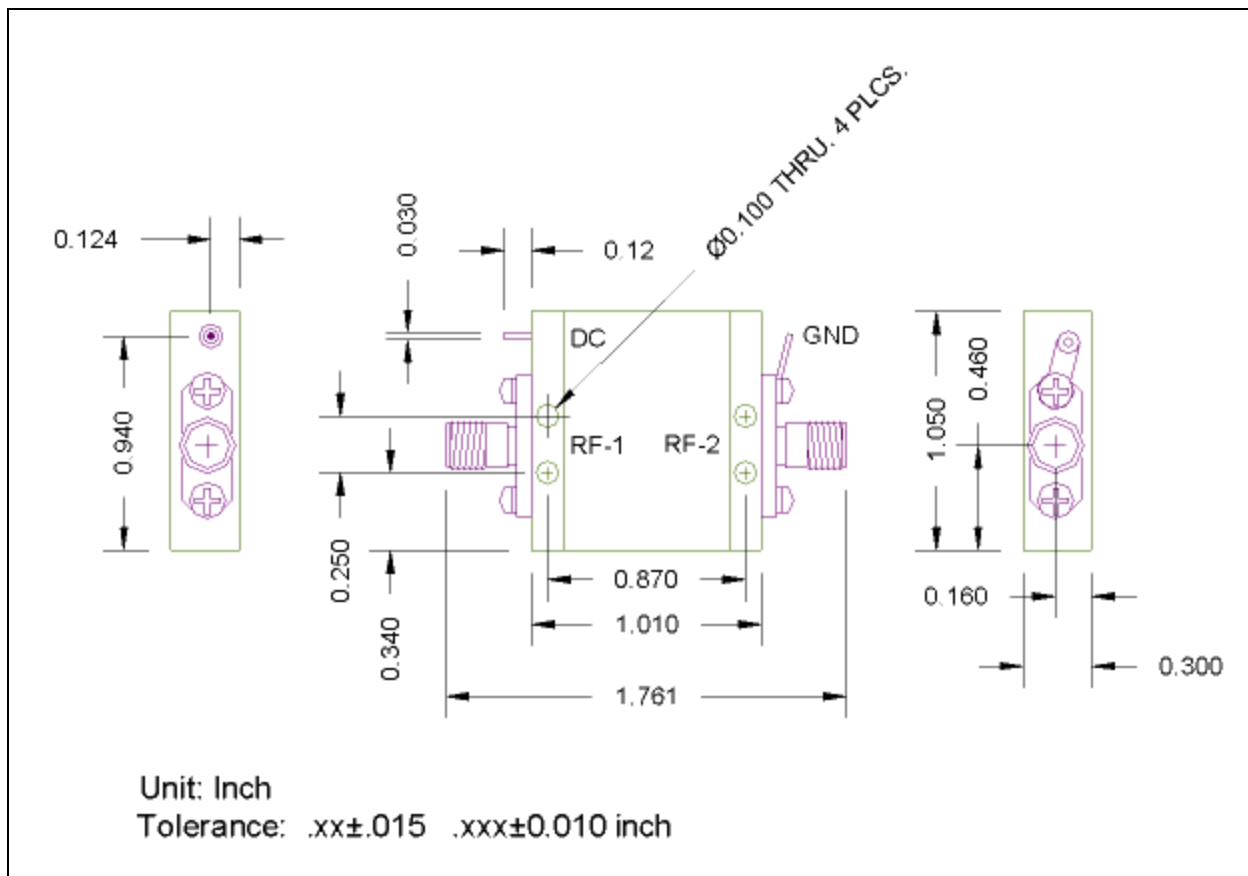


Updated: 10/25/2007

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Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
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RF-1	SMA-F	1 IN	I	RF INPUT SIGNAL
RF-2	SMA-F	1 OUT	O	RF OUTPUT SIGNAL
DC	EMI Filter	1 +12 V	I	DC INPUT (+9 V TO 15 V)
GND	GROUND LUG	1 GND	O	GROUND

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